# New Jersey Semi-Conductor Products, Inc.

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## **BYX56 SERIES**

## CONTROLLED AVALANCHE RECTIFIER DIODES

Silicon diodes in a DO-5 metal envelope, capable of absorbing transients and intended for power rectifier applications.

The series consists of the following types:

Normal polarity (cathode to stud): BYX56-600 to BYX56-1400. Reverse polarity (anode to stud): BYX56-600R to BYX56-1400R.

15.3 max

#### QUICK REFERENCE DATA

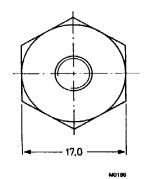
		BYX56	-600(R)	800(R)	1000(R)	1200(R)	1400(F	<u>(</u> )
Crest working reverse voltage	$v_{\text{RWM}}$	max.	600	800	1000	1200	1400	٧
Reverse avalanche breakdown voltage	V <sub>(BR)R</sub>	>	750	1000	1250	1450	1650	٧
Average forward current	i <sub>F</sub> (AV)	max.			48			Α
Non-repetitive peak forward current	FSM	max.			800			Α
Non-repetitive peak reverse power dissipation	PRSM	max.			40			k۷

### **MECHANICAL DATA**

6.35 max

Fig. 1 DO-5

3.8 min 8.0 max 3.0 min (flat)



Dimensions in mm

Net mass: 22 g

Diameter of clearance hole: max. 6.5 mm

Accessories supplied on request: see ACCESSORIES section

Supplied with device: 1 nut, 1 lock washer.

<u>Nut dimensions across the flats: 11.1 mm.</u>

Torque on nut: min. 1.7 Nm (17 kg cm), max. 3.5 Nm (35 kg cm).

The mark shown applies to normal polarity types.

NJ Semi-Conductors reserves the right to change test conditions, parameter limits and package dimensions without notice. Information furnished by NJ Semi-Conductors is believed to be both accurate and reliable at the time of going to press. However, NJ Semi-Conductors assumes no responsibility for any errors or omissions discovered in its use. NJ Semi-Conductors encourages customers to verify that datasheets are current before placing orders.

Quality Semi-Conductors

**RATINGS** 

Limiting values in accordance with the Absolute Maximum System (IEC134)

Voltages*		BYX56-600(R)		800(R) 1000(R)		1200(R) 1400(F		R)
Crest working reverse voltage	<b>VRWM</b>	max.	600	800	1000	1200	1400	V
Continuous reverse voltage	V <sub>R</sub>	max.	600	800	1000	1200	1400	V
Currents								
Average forward current (averaged over any 20 ms pour to T <sub>mb</sub> = 112 °C at T <sub>mb</sub> = 125 °C	eriod)			IF(AV			48 40	A A
R.M.S. forward current				IF(RMS) max		x. 75		Α
Repetitive peak forward current				IFRM max		x. 450		Α
Non-repetitive peak forward c t = 10 ms (half sine-wave); T <sub>j</sub> = 175 °C prior to surge; with reapplied V <sub>RWMmax</sub>	urrent			<sup>I</sup> FS <b>M</b>	max	τ.	800	A
$I^2$ t for fusing (t < 10 ms)				i²t max		x. 3200		A²s
Reverse power dissipation								
Repetitive peak reverse power $t = 10 \mu s$ (square-wave; $f = 5$ $T_j = 175  ^{\circ}C$	•	n		PRRM	max n	: <b>.</b>	6.5	kW
Non-repetitive peak reverse po t = 10 μs (square-wave)	wer dissip	ation						
$T_j = 25$ °C prior to surge $T_j = 175$ °C prior to surge				PRSM PRSM	max max		40 6.5	kW kW
Temperatures								
Storage temperature			T <sub>stg</sub>		-55 to +		ос	
Junction temperature				τ <sub>j</sub>	max		175	οС
THERMAL RESISTANCE								
From junction to mounting ba	ise			R <sub>th i-r</sub>	mb =		8.0	oc/w
From mounting base to heatsink				R <sub>th mb-h</sub> =			0.2	
Transient thermal impedance; t = 1 ms				Z <sub>th j-h</sub>		C	.03	oc/w

## **CHARACTERISTICS**

		BYX56600(R)		800(R) 1000(R)		1200(R)	1400(R)	
Forward voltage IF = 150 A; T <sub>j</sub> = 25 °C	VF	<	1.8	1.8	1.8	1.8	1.8	 V*
Reverse avalanche breakdo voltage I <sub>R</sub> = 5 mA; T <sub>j</sub> = 25 °C	wn V <sub>(BR)R</sub>	·. > <	750 2400	1000 2400	1250 2400	1450 2400	1650 2400	v v
Reverse current VR = VRWMmax; Tj = 125 °C	I <sub>R</sub>	<	1.6	1.6	1.6	1.6	1.6	mA

## **OPERATING NOTES**

The top connector should neither be bent nor twisted; it should be soldered into the circuit so that there is no strain on it.

During soldering the heat conduction to the junction should be kept to a minimum by using a thermal shunt.

